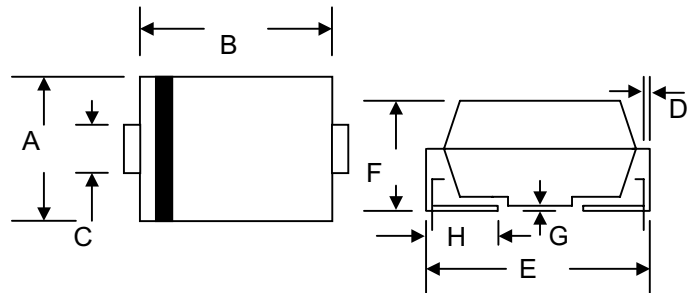


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Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Surge Overload Rating to 50A Peak
- Low Power Loss
- Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.093 grams (approx.)

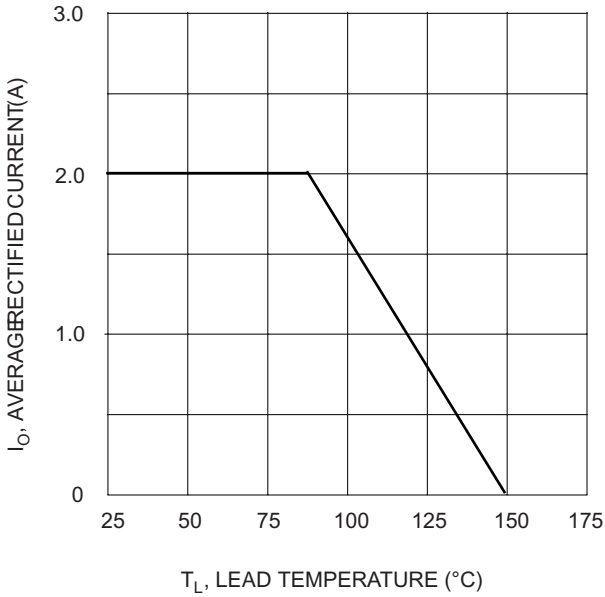
SMB/DO-214AA				
Dim	Min	Max	Min	Max
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.91	2.11	0.075	0.083
D	0.152	0.305	0.006	0.012
E	5.08	5.59	0.2	0.220
F	2.13	2.44	0.084	0.096
G	0.051	0.203	0.002	0.008
H	0.76	1.27	0.029	0.05
			in mm	In inch

Maximum Ratings and Electrical Characteristics @ $T_A=25^{\circ}\text{C}$ unless otherwise specified

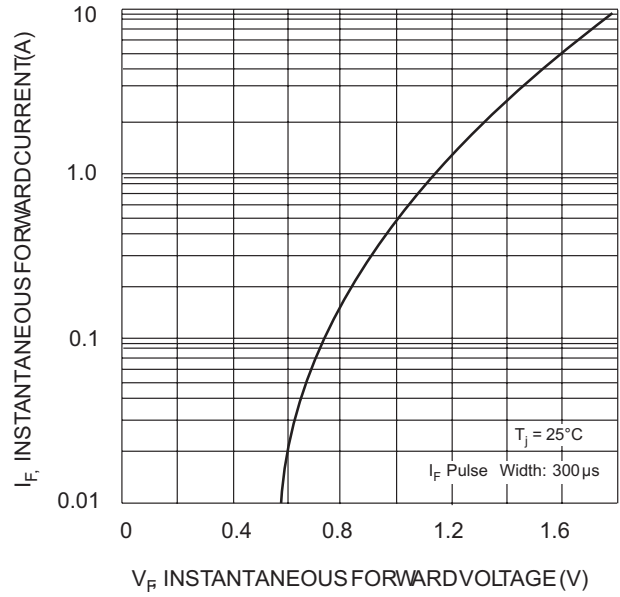
Characteristic	Symbol	FR2A	FR2B	FR2D	FR2G	FR2J	FR2K	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	200	400	600	800	V
Working Peak Reverse Voltage	V_{RWM}							
DC Blocking Voltage	V_R							
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	V
Average Rectified Output Current @ $T_L = 90^{\circ}\text{C}$	I_o	2.0						A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50						A
Forward Voltage @ $I_F = 2.0\text{A}$	V_{FM}	1.30						V
Peak Reverse Current @ $T_A = 25^{\circ}\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^{\circ}\text{C}$	I_{RM}	5.0 300						μA
Reverse Recovery Time (Note 1)	t_{rr}	150				250	500	nS
Typical Junction Capacitance (Note 2)	C_j	50						pF
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$	20						K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-50 to +150						$^{\circ}\text{C}$

Note: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$,
2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
3. Mounted on P.C. Board with 8.0mm^2 land area.

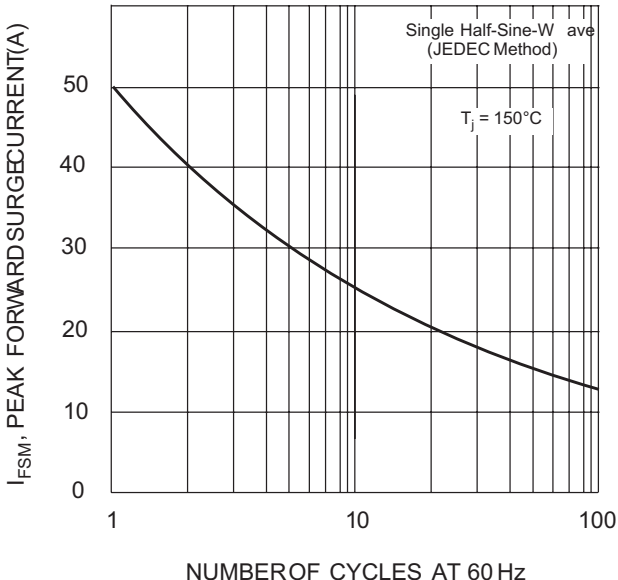
Data Sheet 2707, Rev. -



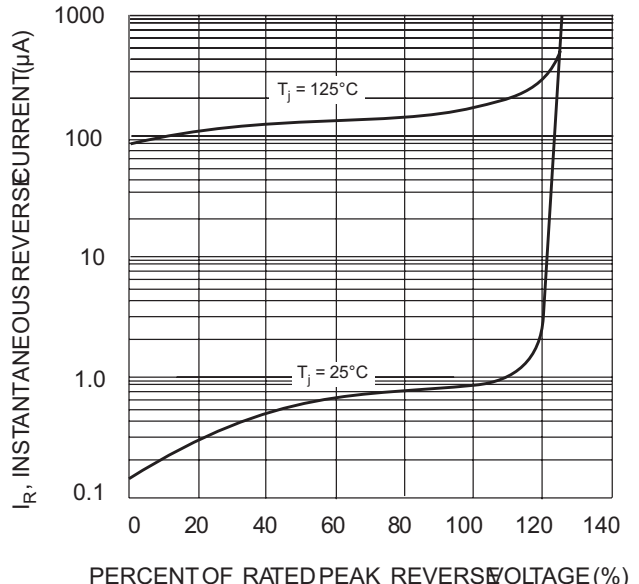
T_L , LEAD TEMPERATURE ($^{\circ}C$)
Fig. 1 Forward Current Derating Curve



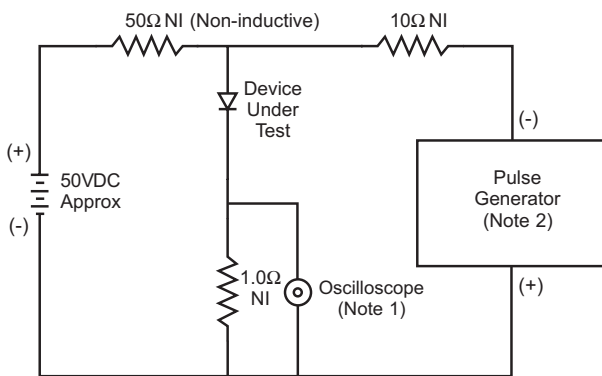
V_F INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typical Forward Characteristics



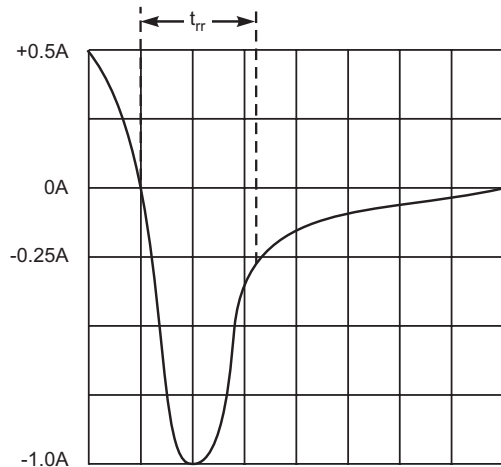
NUMBER OF CYCLES AT 60 Hz
Fig. 3 Forward Surge Current Derating Curve



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 4, Typical Reverse Characteristics



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0M Ω , 2pF.
2. Rise Time = 10ns max. Input Impedance = 50 Ω .



Set time base for 10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

TECHNICAL DATA

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